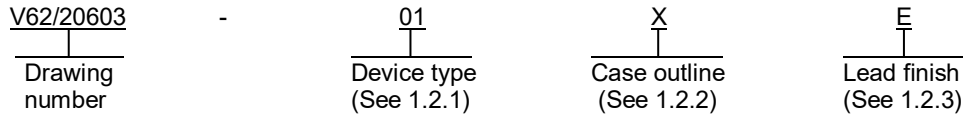




1. SCOPE

1.1 Scope. This drawing documents the general requirements of a high performance Quad Channel, 256-Position, SPI, Nonvolatile Digital Potentiometer microcircuit, with an operating temperature range of -55°C to +125°C.

1.2 Vendor Item Drawing Administrative Control Number. The manufacturer's PIN is the item of identification. The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation:



1.2.1 Device type(s).

<u>Device type</u>	<u>Generic</u>	<u>Circuit function</u>
01	AD5144-EP	Quad Channel, 256-Position, SPI, Nonvolatile Digital Potentiometer

1.2.2 Case outline(s). The case outlines are as specified herein.

<u>Outline letter</u>	<u>Number of pins</u>	<u>JEDEC PUB 95</u>	<u>Package style</u>
X	20	JEDEC MO-153-AC	Small Outline Transistor Package

1.2.3 Lead finishes. The lead finishes are as specified below or other lead finishes as provided by the device manufacturer:

<u>Finish designator</u>	<u>Material</u>
A	Hot solder dip
B	Tin-lead plate
C	Gold plate
D	Palladium
E	Gold flash palladium
F	Tin-lead alloy (BGA/CGA)
Z	Other

<b>DLA LAND AND MARITIME COLUMBUS, OHIO</b>	SIZE <b>A</b>	CODE IDENT NO. <b>16236</b>	DWG NO. <b>V62/20603</b>
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1.3 Absolute maximum ratings. 1/ 2/

V <sub>DD</sub> to GND .....	-0.3 V to +7.0 V
V <sub>SS</sub> to GND .....	+0.3 V to -7.0 V
V <sub>DD</sub> to V <sub>SS</sub> .....	7 V
V <sub>LOGIC</sub> to GND .....	-0.3 V to V <sub>DD</sub> +0.3 V or +7.0 V (whichever is less)
V <sub>A</sub> , V <sub>W</sub> , V <sub>B</sub> to GND .....	V <sub>SS</sub> - 0.3 V, V <sub>DD</sub> + 0.3 V
IA, IW, IB:	
Pulsed 3/, R <sub>AW</sub> = 10 kΩ	
Frequency > 10 kHz .....	±6 mA/d 4/
Frequency ≤ 10 kHz .....	±6 mA/√d 4/
Digital Inputs .....	-0.3 V to V <sub>LOGIC</sub> +0.3 V or +7.0 V (whichever is less)
Operating Temperature Range, T <sub>A</sub> 5/ .....	-55°C to +125°C
Maximum Junction Temperature, T <sub>J</sub> Maximum .....	150°C
Storage Temperature Range .....	-65°C to +150°C
Reflow Soldering:	
Peak Temperature .....	260°C
Time at Peak Temperature .....	20 sec to 40 sec
Package Power Dissipation .....	(T <sub>J</sub> max - T <sub>A</sub> ) / θ <sub>JA</sub>
Field Induced Charged Device Model (FICDM) .....	1.5 kV

1.4 Thermal Resistance.

Case outline	θ <sub>JA</sub> 6/	θ <sub>JC</sub>	Unit
Case X	143	45	°C/W

- 1/ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.
- 2/ T<sub>A</sub> = 25°C, unless otherwise noted.
- 3/ The maximum terminal current is bounded by the maximum current handling of the switches, the maximum power dissipation of the package, and the maximum applied voltage across any two of the A, B, and W terminals at a given resistance.
- 4/ d = pulse duty factor.
- 5/ T<sub>A</sub> includes programming of EEPROM memory.
- 6/ Thermal impedance simulated values are based on a JEDEC 2S2P thermal test board, still air (0 m/sec airflow). See JEDEC JESD-51.

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2. APPLICABLE DOCUMENTS

JEDEC – SOLID STATE TECHNOLOGY ASSOCIATION (JEDEC)

- JEP95 – Registered and Standard Outlines for Semiconductor Devices
- JESD51 – Methodology for the Thermal Measurement of Component Packages (Single Semiconductor Device).

(Applications for copies should be addressed to the Electronic Industries Alliance, 3103 North 10th Street, Suite 240–S, Arlington, VA 22201-2107 or online at <https://www.jedec.org>)

3. REQUIREMENTS

3.1 Marking. Parts shall be permanently and legibly marked with the manufacturer’s part number as shown in 6.3 herein and as follows:

- A. Manufacturer’s name, CAGE code, or logo
- B. Pin 1 identifier
- C. ESDS identification (optional)

3.2 Unit container. The unit container shall be marked with the manufacturer’s part number and with items A and C (if applicable) above.

3.3 Electrical characteristics. The maximum and recommended operating conditions and electrical performance characteristics are as specified in 1.3, 1.4, and table I herein.

3.4 Design, construction, and physical dimension. The design, construction, and physical dimensions are as specified herein.

3.5 Diagrams.

3.5.1 Case outline. The case outline shall be as shown in 1.2.2 and figure 1.

3.5.2 Terminal connections. The terminal connections shall be as shown in figure 2.

3.5.3 Terminal function. The terminal function shall be as shown in figure 3.

3.5.4 Functional block diagram. The functional block diagram shall be as shown in figure 4.

3.5.5 Input Shift Register Contents. The Input Shift Register Contents shall be as shown in figure 5.

3.5.6 SPI Serial Interface Timing Diagram, CPOL = 0, CPHA = 1. The SPI Serial Interface Timing Diagram, CPOL = 0, CPHA = 1 shall be as shown in figure 6.

3.5.7 SPI Serial Interface Timing Diagram, CPOL = 1, CPHA = 0. The SPI Serial Interface Timing Diagram, CPOL = 1, CPHA = 0 shall be as shown in figure 7.

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TABLE I. Electrical performance characteristics. 1/

Test	Symbol	Test conditions 2/	Limits			Unit
			Min	Typ 3/	Max	
<b>DC CHARACTERISTICS—RHEOSTAT MODE (ALL RESISTIVE DIGITAL-TO-ANALOG CONVERTERS (RDACs))</b>						
Resolution	N		8			Bits
Resistor Integral Nonlinearity 4/	R-INL	Terminal A and Terminal B resistor ( $R_{AB}$ ) = 10 k $\Omega$ $V_{DD} \geq 2.7$ V $V_{DD} < 2.7$ V	-2 -5	$\pm 0.2$ $\pm 1.5$	+2 +5	LSB LSB
Resistor Differential Nonlinearity 4/	R-DNL		-0.5	$\pm 0.2$	+0.5	LSB
Nominal Resistor Tolerance	$\Delta R_{AB}/R_{AB}$		-8	$\pm 1$	+8	%
Resistance Temperature Coefficient 5/	$(\Delta R_{AB}/R_{AB})/\Delta T \times 10^6$	Code = full scale		35		ppm/ $^{\circ}$ C
Wiper Resistance 5/	RW	Code = zero scale, $R_{AB} = 10$ k $\Omega$		55	125	$\Omega$
Bottom Scale or Top Scale	$R_{BS}$ or $R_{TS}$	$R_{AB} = 10$ k $\Omega$		40	80	$\Omega$
Nominal Resistance Match	$R_{AB1}/R_{AB2}$	Code = 0xFF	-1	$\pm 0.2$	+1	%
<b>DC CHARACTERISTICS—POTENTIOMETER DIVIDER MODE (ALL RDACs)</b>						
Integral Nonlinearity 6/	INL	$R_{AB} = 10$ k $\Omega$	-1	$\pm 0.2$	+1	LSB
Differential Nonlinearity 6/	DNL		-0.5	$\pm 0.2$	+0.5	LSB
Full-Scale Error	$V_{WFSE}$	$R_{AB} = 10$ k $\Omega$	-2.5	-0.1		LSB
Zero-Scale Error	$V_{WZSE}$	$R_{AB} = 10$ k $\Omega$		1.2	3	LSB
Voltage Divider Temperature Coefficient 5/	$(\Delta V_W/V_W)/\Delta T \times 10^6$	Code = half scale		$\pm 5$		ppm/ $^{\circ}$ C
<b>RESISTOR TERMINALS</b>						
Maximum Continuous Current	$I_A, I_B,$ and $I_W$	$R_{AB} = 10$ k $\Omega$	-6		+6	mA
Terminal Voltage Range 7/			$V_{SS}$		$V_{DD}$	V
Capacitance A, Capacitance B 5/	$C_A, C_B$	f = 1 MHz, measured to GND, code = half scale, $R_{AB} = 10$ k $\Omega$		25		pF
Capacitance W 5/	$C_W$	f = 1 MHz, measured to GND, code = half scale, $R_{AB} = 10$ k $\Omega$		12		pF
Common-Mode Leakage Current 5/		Terminal A voltage ( $V_A$ ) = wiper terminal voltage ( $V_W$ ) = Terminal B voltage ( $V_B$ )	-500	$\pm 15$	+500	nA
<b>DIGITAL INPUTS</b>						
Input Logic High	$V_{INH}$	$V_{LOGIC} = 1.8$ V to 2.3 V $V_{LOGIC} = 2.3$ V to 5.5 V	$0.8 \times V_{LOGIC}$ $0.7 \times V_{LOGIC}$			V V
Input Logic Low	$V_{INL}$				$0.2 \times V_{LOGIC}$	V
Input Hysteresis 5/	$V_{HYST}$		$0.1 \times V_{LOGIC}$			V
Input Current 5/	$I_{IN}$				$\pm 1$	$\mu$ A
Input Capacitance 5/	$C_{IN}$			5		pF

See footnote at end of table.

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TABLE I. Electrical performance characteristics - Continued. 1/

Test	Symbol	Test conditions <u>2/</u>	Limits			Unit
			Min	Typ <u>3/</u>	Max	
<b>DIGITAL OUTPUTS</b>						
Output High Voltage	V <sub>OH</sub>	Pull-up resistor (R <sub>PULL-UP</sub> ) = 2.2 kΩ to V <sub>LOGIC</sub>		V <sub>LOGIC</sub>		V
Output Low Voltage	V <sub>OL</sub>	Sink current (I <sub>SINK</sub> ) = 3 mA I <sub>SINK</sub> = 6 mA, V <sub>LOGIC</sub> > 2.3 V			0.4 0.6	V V
Three-State Leakage Current			-1		+1	μA
Three-State Output Capacitance				2		pF
<b>POWER SUPPLIES</b>						
Single-Supply Range		V <sub>SS</sub> = GND	2.3		5.5	V
Dual-Supply Range			±2.25		±2.75	V
Logic Supply Range		Single supply, V <sub>SS</sub> = GND Dual supply, V <sub>SS</sub> < GND	1.8 2.25		V <sub>DD</sub> V <sub>DD</sub>	V
Positive Supply Current	I <sub>DD</sub>	V <sub>INH</sub> = V <sub>LOGIC</sub> or V <sub>INL</sub> = GND V <sub>DD</sub> = 5.5 V V <sub>DD</sub> = 2.3 V		0.7 400	5.5	μA nA
Negative Supply Current	I <sub>SS</sub>	V <sub>INH</sub> = V <sub>LOGIC</sub> or V <sub>INL</sub> = GND	-5.5	-0.7		μA
EEPROM Store Current <u>5/ 8/</u>	I <sub>DD_EEPROM_STORE</sub>	V <sub>INH</sub> = V <sub>LOGIC</sub> or V <sub>INL</sub> = GND		2		mA
EEPROM Read Current <u>5/ 9/</u>	I <sub>DD_EEPROM_READ</sub>	V <sub>INH</sub> = V <sub>LOGIC</sub> or V <sub>INL</sub> = GND		320		μA
Logic Supply Current	I <sub>LOGIC</sub>	V <sub>INH</sub> = V <sub>LOGIC</sub> or V <sub>INL</sub> = GND		0.05	1.4	μA
Power Dissipation <u>10/</u>	P <sub>DISS</sub>	V <sub>INH</sub> = V <sub>LOGIC</sub> or V <sub>INL</sub> = GND		3.5		μW
Power Supply Rejection Ratio	PSRR	ΔV <sub>DD</sub> /ΔV <sub>SS</sub> = V <sub>DD</sub> ± 10%, code = full scale		-66	-60	dB
<b>DYNAMIC CHARACTERISTICS</b> <u>11/</u>						
Bandwidth	BW	-3 dB, R <sub>AB</sub> = 10 kΩ		3		MHz
Total Harmonic Distortion	THD	V <sub>DD</sub> /V <sub>SS</sub> = ±2.5 V, V <sub>A</sub> = 1 V rms, V <sub>B</sub> = 0 V, f = 1 kHz		-80		dB
Resistor Noise Density	e <sub>N_WB</sub>	Code = half scale, T <sub>A</sub> = 25°C, f = 10 kHz, R <sub>AB</sub> = 10 kΩ		7		nV/√Hz
VW Settling Time	t <sub>s</sub>	V <sub>A</sub> = 5 V, V <sub>B</sub> = 0 V, from zero scale to full scale, ±0.5 LSB error band, R <sub>AB</sub> = 10 kΩ		2		μs
Crosstalk (CW1/CW2)	C <sub>T</sub>	R <sub>AB</sub> = 10 kΩ		10		nV-sec
Analog Crosstalk	C <sub>TA</sub>			-90		dB
Endurance <u>12/</u>		T <sub>A</sub> = 25°C		1		Mcycles
		-40°C < T <sub>A</sub> < +125°C	100			kcycles
Data Retention <u>13/ 14/</u>				50		Years

See footnote at end of table.

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TABLE I. Electrical performance characteristics - Continued. 1/

Test <u>16/</u>	Symbol	Test conditions <u>15/</u>	Limits			Unit
			Min	Typ	Max	
<b>INTERFACE TIMING SPECIFICATIONS</b>						
<b>SPI Interface</b>						
SCLK cycle time	t1	V <sub>LOGIC</sub> > 1.8 V	20			ns
		V <sub>LOGIC</sub> = 1.8 V	30			
SCLK high time	t2	V <sub>LOGIC</sub> > 1.8 V	10			
		V <sub>LOGIC</sub> = 1.8 V	15			
SCLK low time	t3	V <sub>LOGIC</sub> > 1.8 V	10			
		V <sub>LOGIC</sub> = 1.8 V	15			
$\overline{\text{SYNC}}$ to SCLK falling edge setup time	t4		10			
Data setup time	t5		5			
Data hold time	t6		5			
$\overline{\text{SYNC}}$ rising edge to next SCLK fall ignored	t7		10			
Minimum $\overline{\text{SYNC}}$ high time	t8 <u>17/</u>		20			
SCLK rising edge to SDO valid	t9 <u>18/</u>			50		
$\overline{\text{SYNC}}$ rising edge to SDO pin disable	t10				500	
Start-up time (not shown in Figure 6 and Figure 7)	t <sub>POWER-UP</sub>				75	μs

See footnote at end of table.

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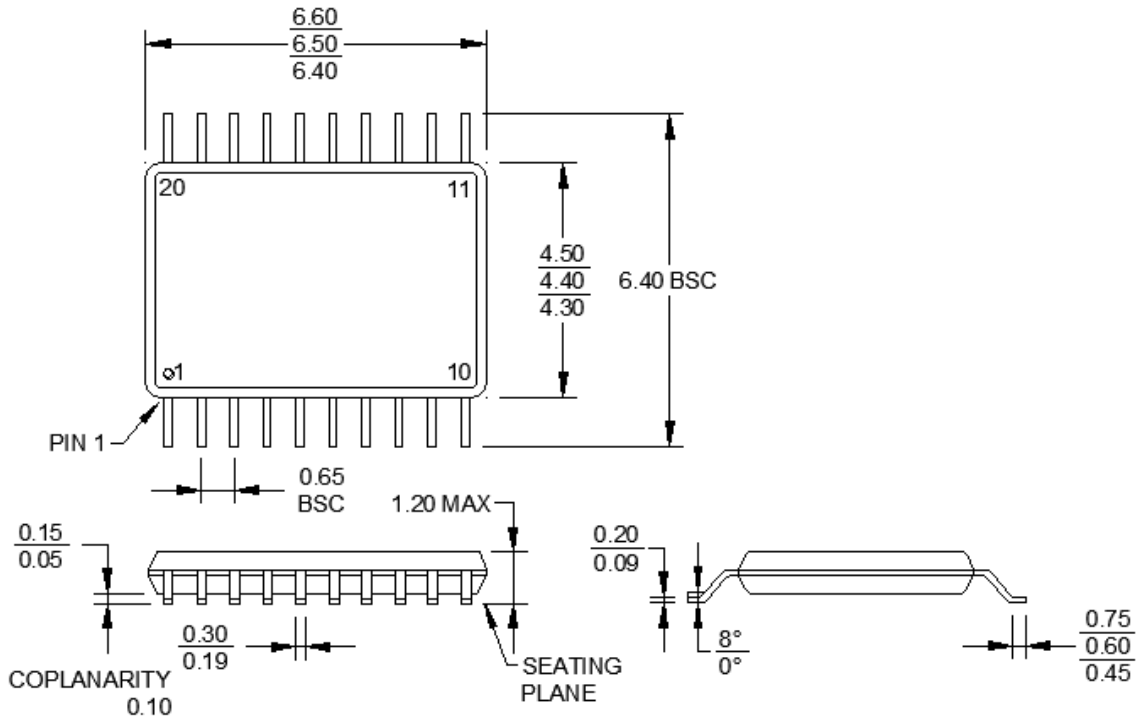
TABLE I. Electrical performance characteristics - Continued. 1/

- 1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.
- 2/  $V_{DD} = 2.3\text{ V to }5.5\text{ V}$  and  $V_{SS} = 0\text{ V}$  for the single-supply range,  $V_{DD} = 2.25\text{ V to }2.75\text{ V}$  and  $V_{SS} = -2.25\text{ V to }-2.75\text{ V}$  for the dual-supply range,  $V_{LOGIC} = 1.8\text{ V to }5.5\text{ V}$ , and  $-55^{\circ}\text{C} < T_A < +125^{\circ}\text{C}$ , unless otherwise noted. See the manufacturer data sheet for the test circuits that define the test conditions used in the Specifications section.
- 3/ Typical values represent average readings at  $25^{\circ}\text{C}$ ,  $V_{DD} = 5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , and  $V_{LOGIC} = 5\text{ V}$ .
- 4/ Resistor integral nonlinearity error (R-INL) is the deviation from an ideal value measured between the maximum resistance and the minimum resistance wiper positions. R-DNL measures the relative step change from ideal between successive tap positions. The maximum wiper current is limited to  $(0.7 \times V_{DD})/R_{AB}$ .
- 5/ Guaranteed by design and characterization, not subject to production test.
- 6/ INL and DNL are measured across the Terminal W and Terminal B voltage (VWB) with the RDAC configured as a potentiometer divider similar to a voltage output DAC.  $V_A = V_{DD}$  and  $V_B = 0\text{ V}$ . DNL specification limits of  $\pm 1\text{ LSB}$  maximum are guaranteed monotonic operating conditions.
- 7/ Resistor Terminal A, Resistor Terminal B, and Resistor Terminal W have no limitations on polarity with respect to each other. Dual-supply operation enables ground referenced bipolar signal adjustment
- 8/  $I_{DD\_EEPROM\_STORE}$  is different from the operating current. Supply current for EEPROM program lasts approximately 30 ms.
- 9/  $I_{DD\_EEPROM\_READ}$  is different from the operating current. Supply current for EEPROM read lasts approximately 20  $\mu\text{s}$ .
- 10/ PDISS is calculated from  $(I_{DD} \times V_{DD}) + (I_{LOGIC} \times V_{LOGIC})$ .
- 11/ All dynamic characteristics use  $V_{DD}/V_{SS} = \pm 2.5\text{ V}$ , and  $V_{LOGIC} = 2.5\text{ V}$ .
- 12/ Endurance is qualified per JEDEC Standard 22, Method A117 to 100,000 cycles measured at  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ .
- 13/ Retention lifetime equivalent at junction temperature ( $T_J$ ) =  $125^{\circ}\text{C}$  per JEDEC Standard 22, Method A117. Retention lifetime based on an activation energy of 1 eV, derates with junction temperature in the Flash/EE memory.
- 14/ 50 years apply to an endurance of 1000 cycles. An endurance of 100,000 cycles has an equivalent retention lifetime of 5 years.
- 15/  $V_{LOGIC} = 1.8\text{ V to }5.5\text{ V}$ , and all specifications  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.
- 16/ All input signals are specified with rising time ( $t_R$ ) = falling time ( $t_F$ ) = 1 ns/V (10% to 90% of  $V_{DD}$ ) and timed from a voltage level of  $(V_{IL} + V_{IH})/2$ .
- 17/ Refer to  $t_{EEPROM\_PROGRAM}$  and  $t_{EEPROM\_READBACK}$  for memory command operations (see the control pins table in the AD5144 manufacturer data sheet for additional information).
- 18/ The pull-up resistance ( $R_{PULL\_UP}$ ) = 2.2 k $\Omega$  to  $V_{DD}$  with a capacitance load of 168 pF.

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Case X



**NOTES:**

1. All linear dimensions are in millimeters.
2. Falls within JEDEC MO-153-AC.

FIGURE 1. Case outline.

<p align="center"><b>DLA LAND AND MARITIME COLUMBUS, OHIO</b></p>	<p align="center">SIZE <b>A</b></p>	<p align="center">CODE IDENT NO. <b>16236</b></p>	<p align="center">DWG NO. <b>V62/20603</b></p>
		<p align="center">REV</p>	<p align="center">PAGE 9</p>

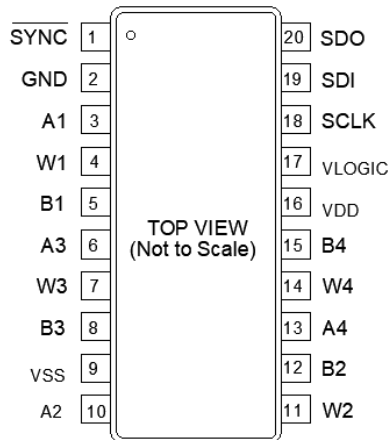


FIGURE 2. Terminal connections.

Pin No.	Mnemonic	Description
1	$\overline{\text{SYNC}}$	Synchronization Data Input, Active Low. When $\overline{\text{SYNC}}$ returns high, data is loaded into the input shift register.
2	GND	Ground Pin, Logic Ground Reference.
3	A1	Terminal A of RDAC 1. $V_{SS} \leq V_A \leq V_{DD}$ .
4	W1	Wiper Terminal of RDAC 1. $V_{SS} \leq V_W \leq V_{DD}$ .
5	B1	Terminal B of RDAC 1. $V_{SS} \leq V_B \leq V_{DD}$ .
6	A3	Terminal A of RDAC 3. $V_{SS} \leq V_A \leq V_{DD}$ .
7	W3	Wiper Terminal of RDAC 3. $V_{SS} \leq V_W \leq V_{DD}$ .
8	B3	Terminal B of RDAC 3. $V_{SS} \leq V_B \leq V_{DD}$ .
9	VSS	Negative Power Supply. Decouple this pin with 0.1 $\mu\text{F}$ ceramic capacitors and 10 $\mu\text{F}$ capacitors.
10	A2	Terminal A of RDAC 2. $V_{SS} \leq V_A \leq V_{DD}$ .
11	W2	Wiper Terminal of RDAC 2. $V_{SS} \leq V_W \leq V_{DD}$ .
12	B2	Terminal B of RDAC 2. $V_{SS} \leq V_B \leq V_{DD}$ .
13	A4	Terminal A of RDAC 4. $V_{SS} \leq V_A \leq V_{DD}$ .
14	W4	Wiper Terminal of RDAC 4. $V_{SS} \leq V_W \leq V_{DD}$ .
15	B4	Terminal B of RDAC 4. $V_{SS} \leq V_B \leq V_{DD}$ .
16	V <sub>DD</sub>	Positive Power Supply. Decouple this pin with 0.1 $\mu\text{F}$ ceramic capacitors and 10 $\mu\text{F}$ capacitors.
17	V <sub>LOGIC</sub>	Logic Power Supply, 1.8 V to V <sub>DD</sub> . Decouple this pin with 0.1 $\mu\text{F}$ ceramic capacitors and 10 $\mu\text{F}$ capacitors.
18	SCLK	Serial Clock Line. Data is clocked in at the logic low transition.
19	SDI	Serial Data Input.
20	SDO	Serial Data Output. SDO is an open-drain output pin that must have an external pull-up resistor.

FIGURE 3. Terminal function.

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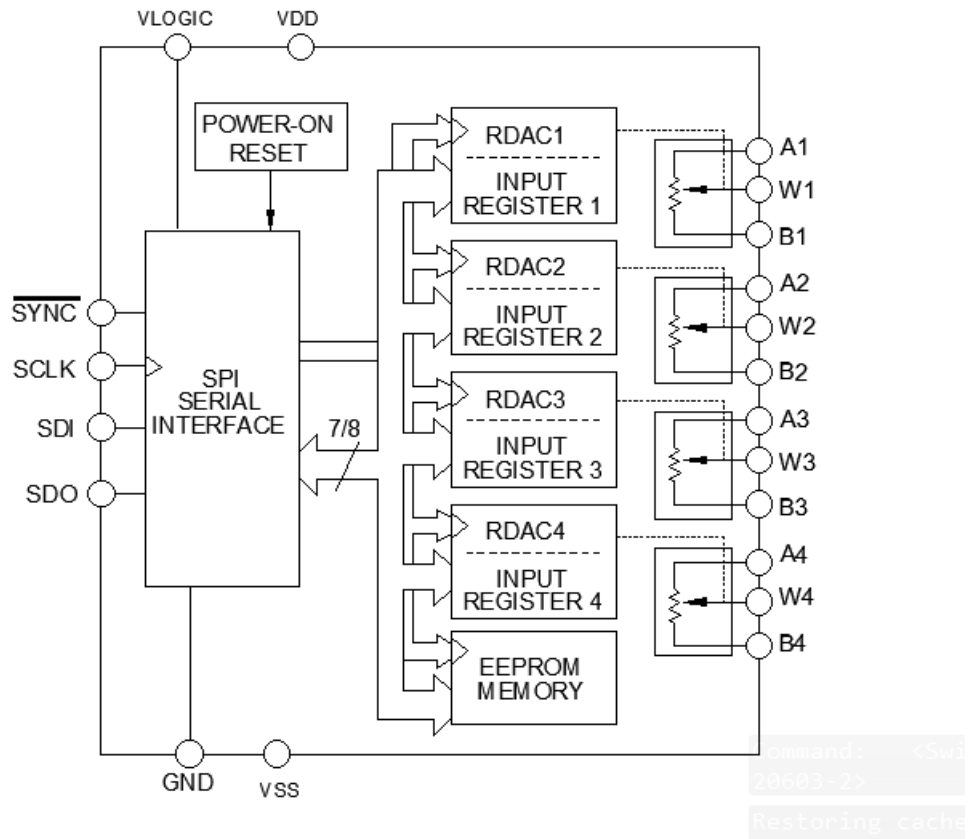


FIGURE 4. Functional block diagram.

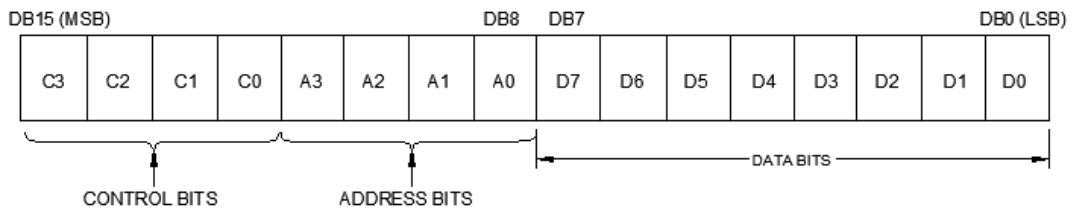


FIGURE 5. Input Shift Register Contents.

<p align="center"><b>DLA LAND AND MARITIME COLUMBUS, OHIO</b></p>	<p align="center">SIZE <b>A</b></p>	<p align="center">CODE IDENT NO. <b>16236</b></p>	<p align="center">DWG NO. <b>V62/20603</b></p>
		<p align="center">REV</p>	<p align="center">PAGE 11</p>

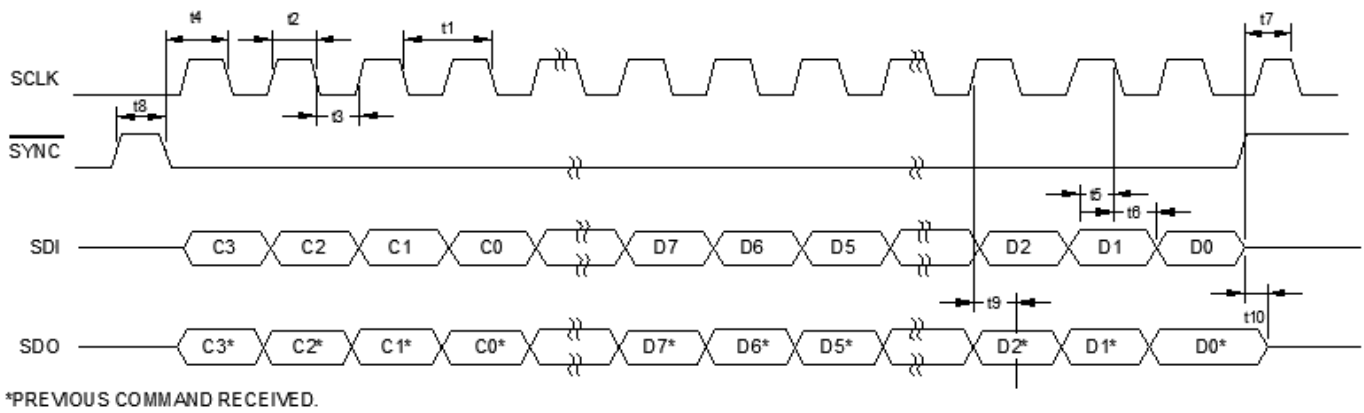


FIGURE 6. SPI Serial Interface Timing Diagram, CPOL = 0, CPHA = 1.

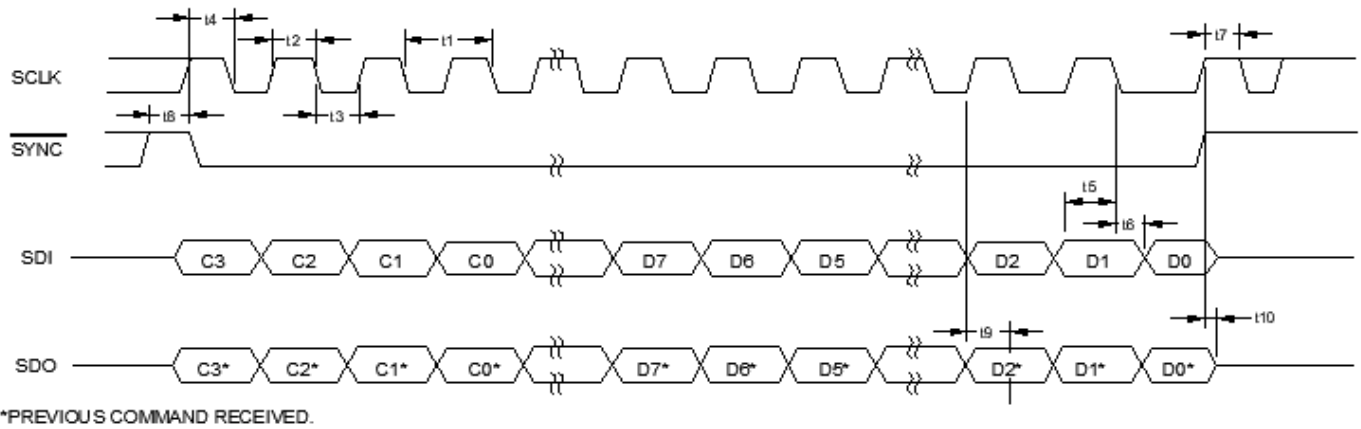


FIGURE 7. SPI Serial Interface Timing Diagram, CPOL = 1, CPHA = 0.

<p align="center"><b>DLA LAND AND MARITIME COLUMBUS, OHIO</b></p>	<p align="center"><b>SIZE A</b></p>	<p align="center"><b>CODE IDENT NO. 16236</b></p>	<p align="center"><b>DWG NO. V62/20603</b></p>
		<p align="center">REV</p>	<p align="center">PAGE 12</p>

4. VERIFICATION

4.1 Product assurance requirements. The manufacturer is responsible for performing all inspection and test requirements as indicated in their internal documentation. Such procedures should include proper handling of electrostatic sensitive devices, classification, packaging, and labeling of moisture sensitive devices, as applicable.

5. PREPARATION FOR DELIVERY

5.1 Packaging. Preservation, packaging, labeling, and marking shall be in accordance with the manufacturer’s standard commercial practices for electrostatic discharge sensitive devices.

6. NOTES

6.1 ESDS. Devices are electrostatic discharge sensitive and are classified as ESDS class 1 minimum.

6.2 Configuration control. The data contained herein is based on the salient characteristics of the device manufacturer’s data book. The device manufacturer reserves the right to make changes without notice. This drawing will be modified as changes are provided.

6.3 Suggested source(s) of supply. Identification of the suggested source(s) of supply herein is not to be construed as a guarantee of present or continued availability as a source of supply for the item. DLA Land and Maritime maintains an online database of all current sources of supply at <https://landandmaritimeapps.dla.mil/programs/smcr/default.aspx>

Vendor item drawing administrative control number <u>1/</u>	Device manufacturer CAGE code	Order Quantity	Vendor part number
V62/20603-01XE	24355	Tube quantities = 75	AD5144TRUZ10-EP
		Reel quantities = 1000	AD5144TRUZ10-EP-RL7

1/ The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation.

CAGE code

24355

Source of supply

Analog Devices  
 1 Technology Way  
 P.O. Box 9106  
 Norwood, MA 02062-9106

<b>DLA LAND AND MARITIME COLUMBUS, OHIO</b>	<b>SIZE A</b>	<b>CODE IDENT NO. 16236</b>	<b>DWG NO. V62/20603</b>
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